

IRK.56, .71 SERIES

STANDARD DIODES

NEW ADD-A-pak™ Power Modules

Features

- Electrically isolated: DBC base plate
- 3500 V_{RMS} isolating voltage
- Standard JEDEC package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Wide choice of circuit configurations
- Large creepage distances
- UL E78996 approved 

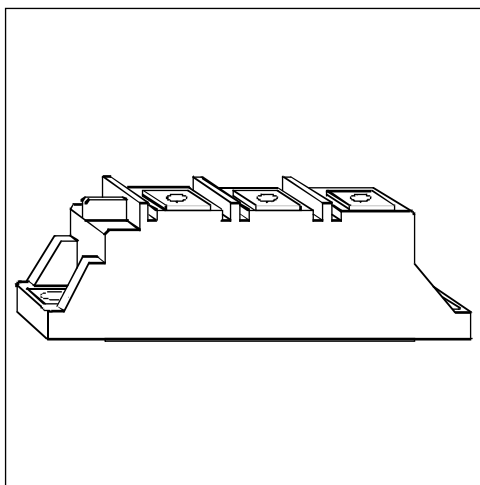
60 A
80 A

Description

These IRK series of NEW ADD-A-paks use power diodes in a variety of circuit configurations. The semiconductor chips are electrically isolated from the base plate, allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges. These modules are intended for general purpose high voltage applications such as battery chargers, welders and plating equipment

Major Ratings and Characteristics

Parameters	IRK.56	IRK.71	Units
$I_{F(AV)}$ @ 100°C	60	80	A
$I_{F(RMS)}$	94	126	A
I_{FSM} @ 50Hz	1600	1790	A
@ 60Hz	1680	1870	A
I^2t @ 50Hz	12.89	15.90	KA ² s
@ 60Hz	11.76	14.53	KA ² s
$I^2\sqrt{t}$	128.9	159	KA ² √s
V _{RRM} range	400 to 1600		V
T _J	- 40 to 150		°C
T _{STG}	- 40 to 150		°C



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Bulletin I27140 rev. B 09/97

International
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ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ 150°C mA
IRK.56/ .71	04	400	500	10
	06	600	700	
	08	800	900	
	10	1000	1100	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

Forward Conduction

Parameter	IRK.56	IRK.71	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Case temperature	60	80	A	180° conduction, half sine wave
	100	100	°C	
$I_{F(AV)}$ Max. average forward current @ Case temperature	55	70	A	180° conduction, half sine wave
	105	108	°C	
$I_{F(RMS)}$ Max. RMS forward current	94	126	A	DC @ 92°C case temperature
I_{FSM} Max. peak, one-cycle forward, non-repetitive surge current	1600	1790	A	t = 10ms No voltage
	1680	1870		t = 8.3ms reapplied
	1350	1500		t = 10ms 100% V_{RRM}
	1420	1570		t = 8.3ms reapplied
I^2t Maximum I^2t for fusing	12.89	15.90	KA ² s	t = 10ms No voltage
	11.76	14.53		t = 8.3ms reapplied
	9.12	11.25		t = 10ms 100% V_{RRM}
	8.32	10.23		t = 8.3ms reapplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	128.9	159.0	KA ² √s	t = 0.1 to 10ms, no voltage reapplied
$V_{F(TO)1}$ Low level value of threshold voltage	0.96	0.83	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
$V_{F(TO)2}$ High level value of threshold voltage	1.03	0.92		$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
r_{f1} Low level value of forward slope resistance	2.81	2.68	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
r_{f2} High level value of forward slope resistance	2.48	2.40		$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
V_{FM} Max. forward voltage drop	1.51	1.50	V	$I_{FM} = \pi \times I_{F(AV)}, T_J = 25^\circ\text{C}, t_p = 400\mu\text{s}$ square wave

Blocking

Parameter	IRK.56	IRK.71	Units	Conditions
I_{RRM} Max. peak reverse leakage current	10		mA	$T_J = 150^\circ\text{C}$
V_{INS} RMS isolation voltage	3500 (1 sec)		V	50 Hz, circuit to base, all terminals shorted

Thermal and Mechanical Specifications

Parameter	IRK.56	IRK.71	Units	Conditions
T _j Junction temperature range	-40 to 150		°C	
T _{stg} Storage temperature range	-40 to 150		°C	
R _{thJC} Max. thermal resistance, junction to case	0.5	0.4	K/W	Per junction, DC operation
R _{thCS} Typical thermal resistance, case to heatsink	0.1		K/W	Mounting surface flat, smooth and greased Flatness < 0.03 mm; roughness < 0.02 mm
T Mounting torque ±10% to heatsink busbar	5 4		Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound
wt Approximate weight	83 (3)		g (oz)	
Case style	TO-240AA			JEDEC

ΔR Conduction (per Junction)

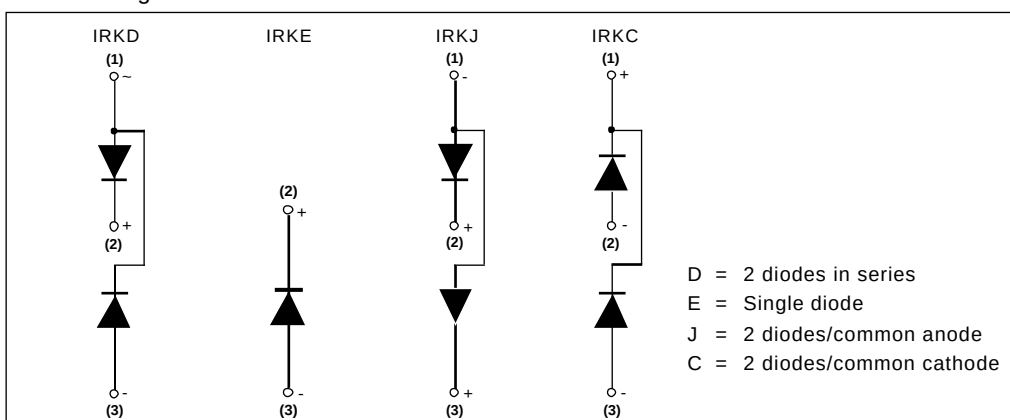
(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Devices	Sine half wave conduction					Rect. wave conduction					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRK.56	0.11	0.13	0.16	0.22	0.32	0.09	0.14	0.17	0.23	0.32	°C/W
IRK.71	0.06	0.08	0.11	0.14	0.21	0.06	0.09	0.11	0.15	0.21	

Ordering Information Table

Device Code				
1	IRK	D	71	/ 16
	(1)	(2)	(3)	(4)
1	- Module type			
2	- Circuit configuration (See Circuit Configuration Table)			
3	- Current code			
4	- Voltage code (See Voltage Ratings Table)			

Circuit Configurations Table



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Outlines Table

All dimensions in millimeters (inches)

(*) For terminals connections, see Circuit Configurations Table

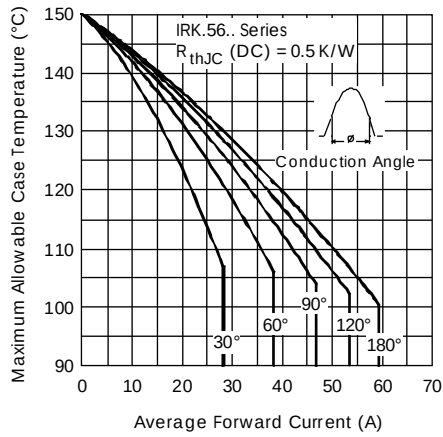


Fig. 1 - Current Ratings Characteristics

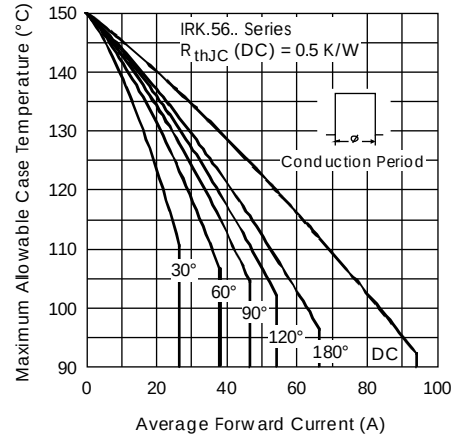


Fig. 2 - Current Ratings Characteristics

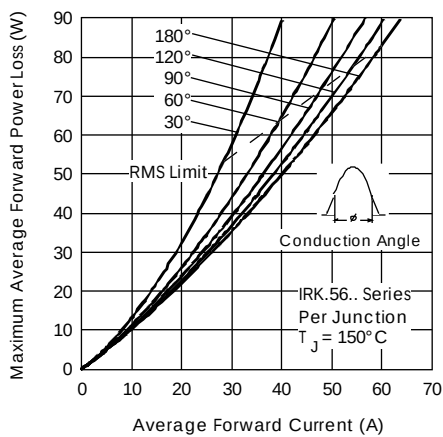


Fig. 3 - Forward Power Loss Characteristics

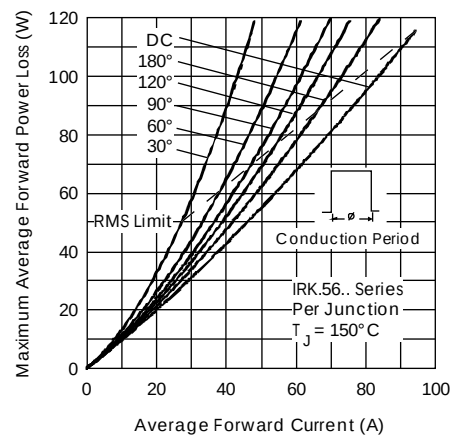


Fig. 4 - Forward Power Loss Characteristics

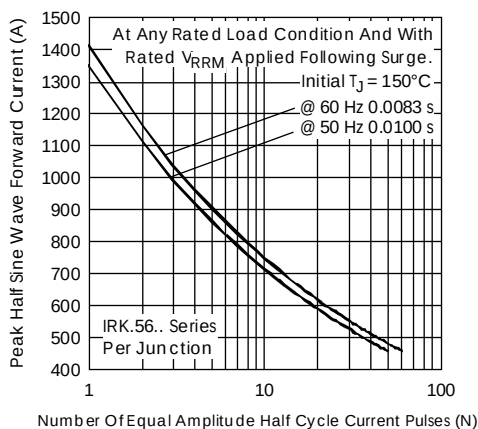


Fig. 5 - Maximum Non-Repetitive Surge Current

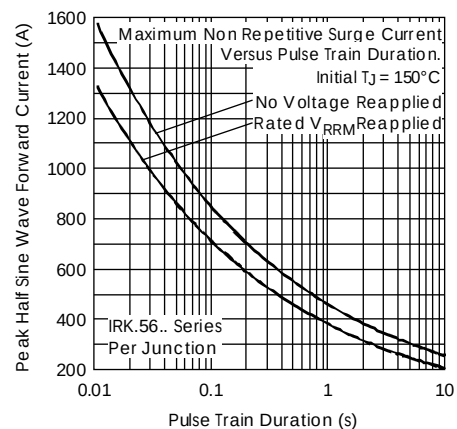


Fig. 6 - Maximum Non-Repetitive Surge Current

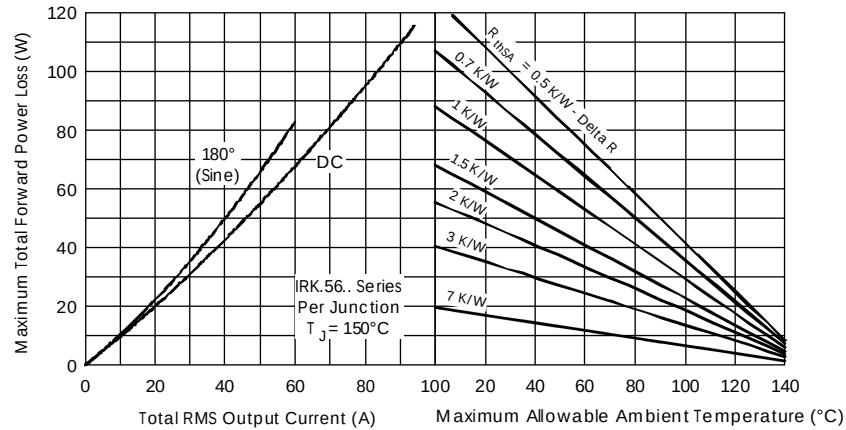


Fig. 7 - Forward Power Loss Characteristics

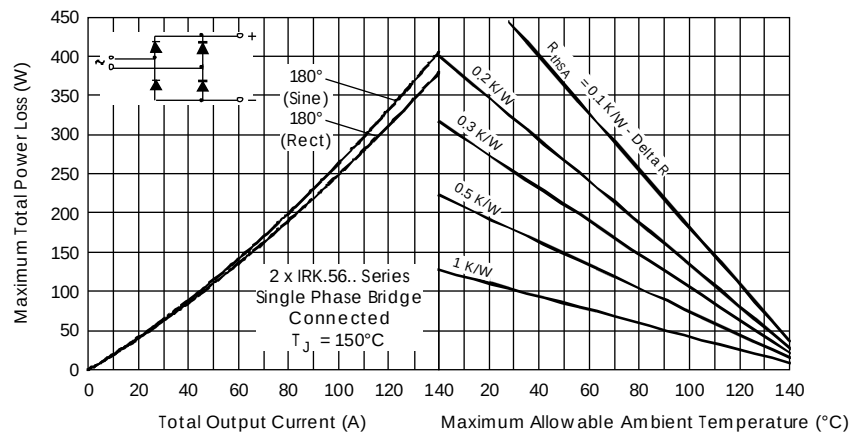


Fig. 8 - Forward Power Loss Characteristics

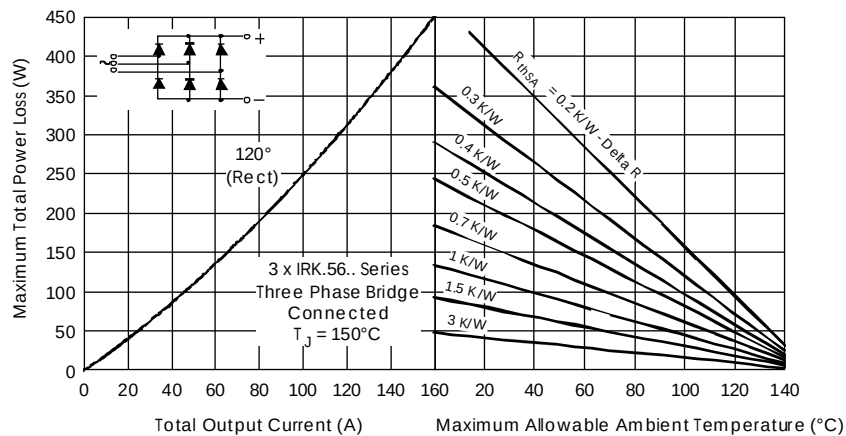


Fig. 9 - Forward Power Loss Characteristics

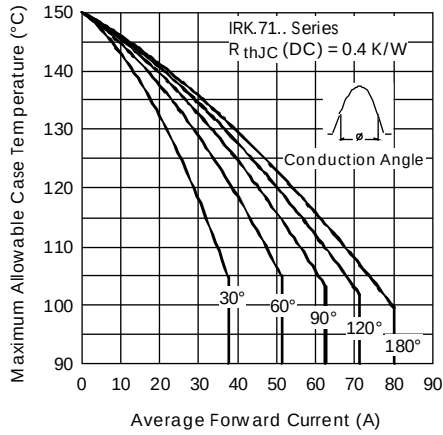


Fig. 10 - Current Ratings Characteristics

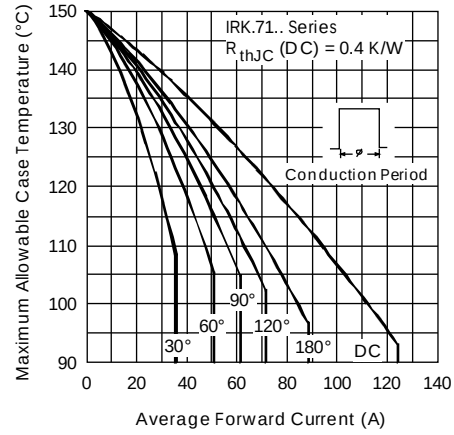


Fig. 11 - Current Ratings Characteristics

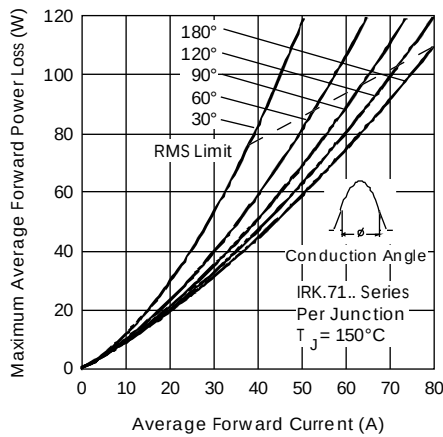


Fig. 12 - Forward Power Loss Characteristics

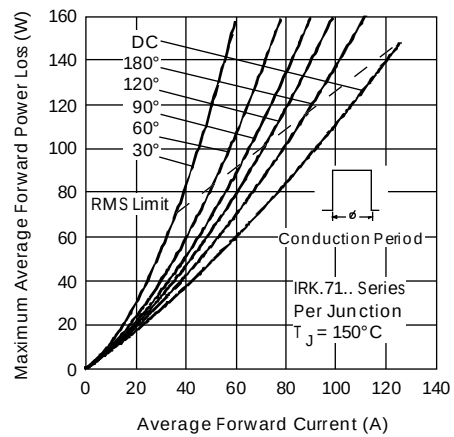


Fig. 13 - Forward Power Loss Characteristics

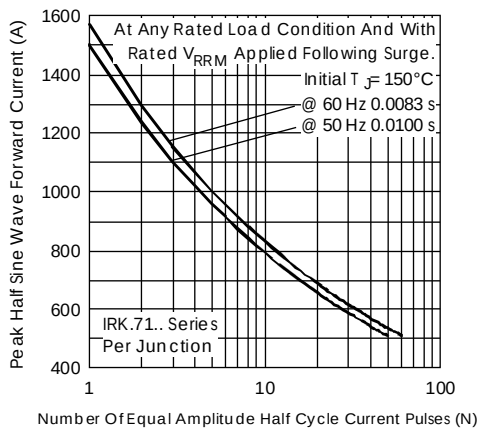


Fig. 14 - Maximum Non-Repetitive Surge Current

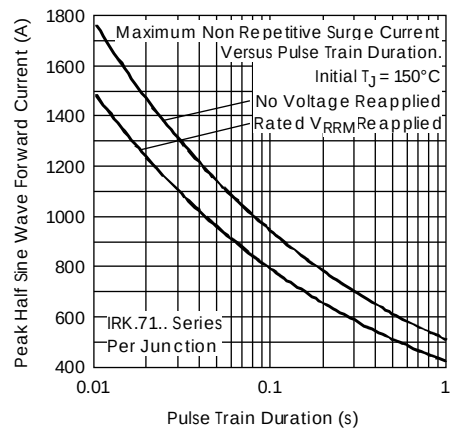


Fig. 15 - Maximum Non-Repetitive Surge Current

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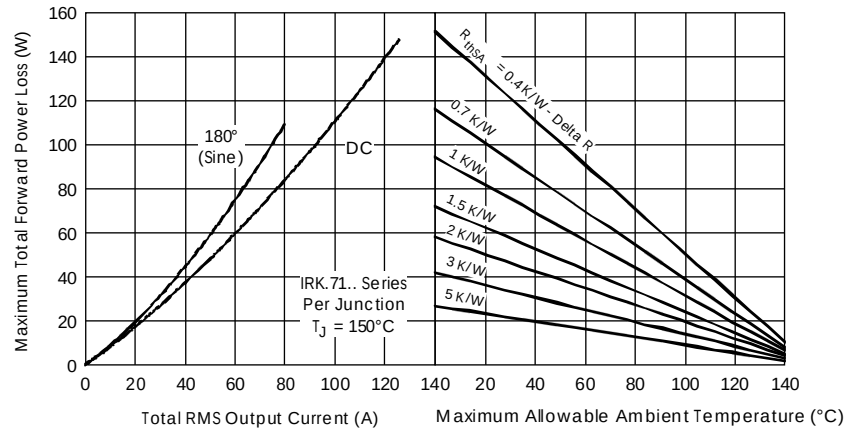


Fig. 16 - Forward Power Loss Characteristics

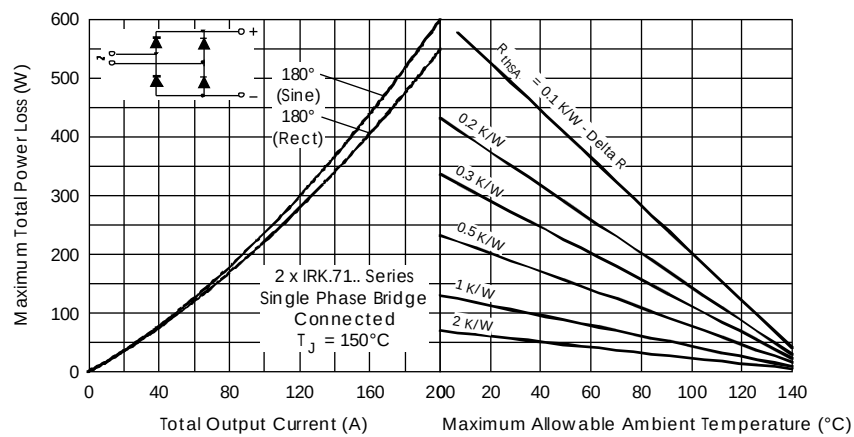


Fig. 17 - Forward Power Loss Characteristics

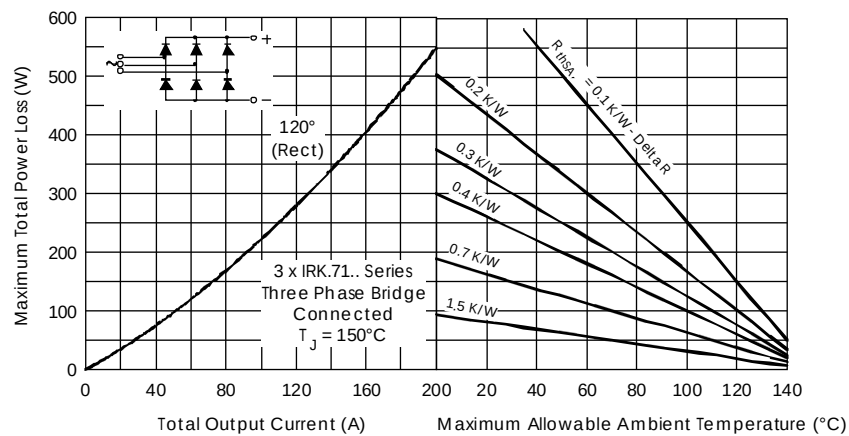


Fig. 18 - Forward Power Loss Characteristics

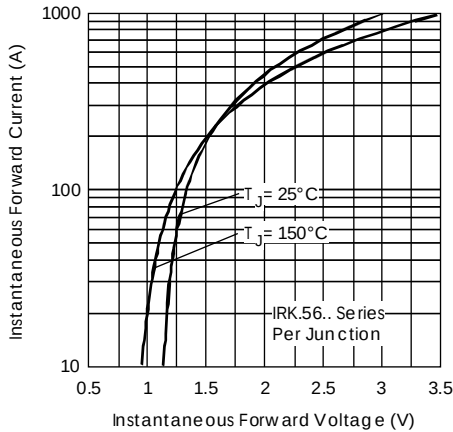


Fig. 19 - Forward Voltage Drop Characteristics

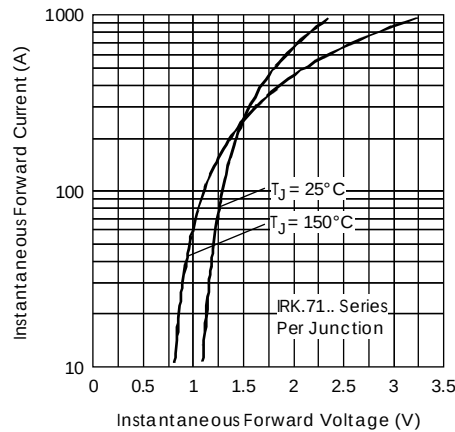


Fig. 20 - Forward Voltage Drop Characteristics

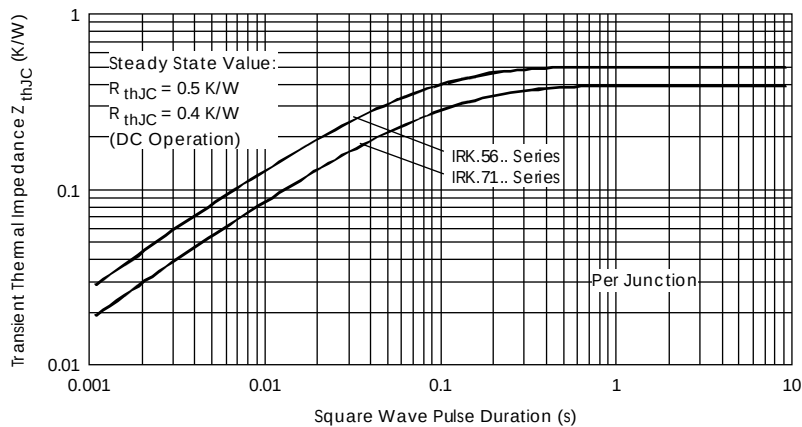


Fig. 21 - Thermal Impedance Z_{thJC} Characteristic